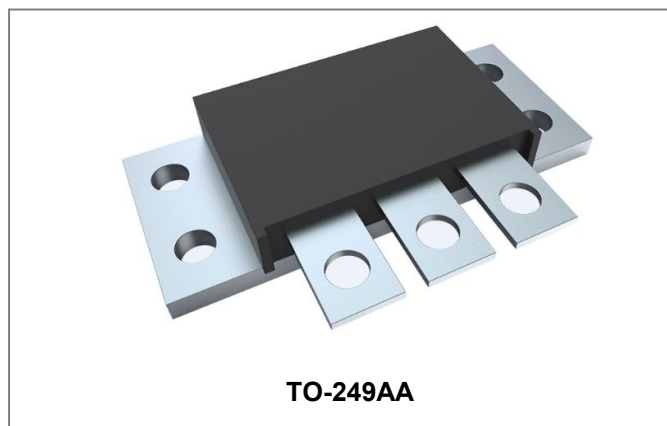


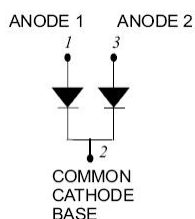
162CMQ030 SCHOTTKY RECTIFIER



Features

- 150 °C T_J operation
- Isolated heatsink
- Low profile, high current package
- Center tap module
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Baseplate: Nickel plated; Terminals: Nickel plated
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Schematic & Pin Configuration



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	30	V
Average Rectified Forward Current	I _{F(AV)}	50% duty cycle @T _C =83°C, rectangular wave form	80(Per Leg) 160(Per Device)	A
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine pulse, T _J = 25 °C	1176	A
Non-Repetitive Avalanche Energy (Peg Leg)	E _{AS}	T _J =25°C, I _{AS} =16A, L=0.56mH	72	mJ
Repetitive Avalanche Current(Peg Leg)	I _{AR}	Current decaying linearly to zero in 1 µsec Frequency limited by T _J max.V _A =1.5×V _R typical	16	A

Electrical Characteristics:

Characteristics	Symbol	Condition	Typ.	Max.	Units
Forward Voltage Drop(Peg Leg)*	V _{F1}	@ 80A, Pulse, T _J = 25 °C	0.53	0.55	V
		@ 160A, Pulse, T _J = 25 °C	0.63	0.69	
	V _{F2}	@ 80A, Pulse, T _J = 125 °C	0.43	0.46	V
		@ 160A, Pulse, T _J = 125 °C	0.51	0.63	
Reverse Current(Peg Leg)*	I _{R1}	@V _R = rated V _R , T _J = 25 °C	0.17	5	mA
	I _{R2}	@V _R = rated V _R , T _J = 125 °C	38	280	mA
Junction Capacitance(Peg Leg)	C _T	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	2800	3700	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

* Pulse width < 300 μs, duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	T _J	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case (Per Leg)	R _{θJC}	DC operation	0.7	°C/W
Typical Thermal Resistance Junction to Case (Per Package)	R _{θJC}	DC operation	0.35	°C/W
Typical Thermal Resistance, case to Heat Sink	R _{θcs}	Mounting surface, smooth and greased	0.10	°C/W
Mounting Torque	T _M	-	40(min)	Kg-cm
			58(max)	
Approximate Weight	wt	-	61	g
Case Style	TO-249(9 pin)			

Ratings and Characteristics Curves

Figure 1
Typical Forward Characteristics

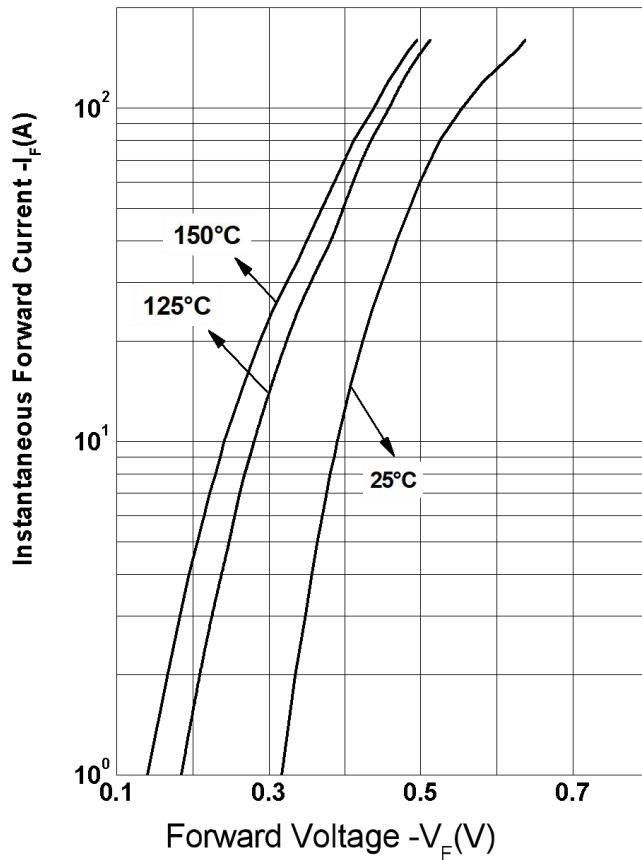


Figure 2
Typical Reverse Characteristics

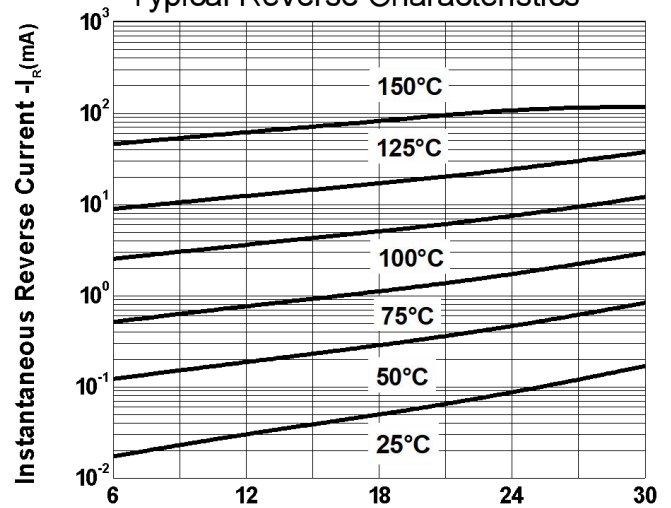
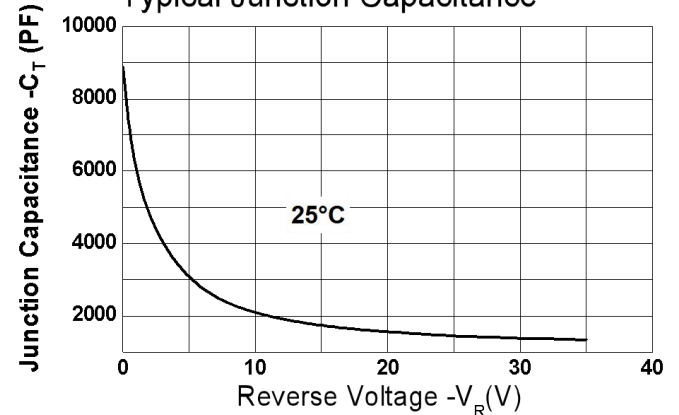
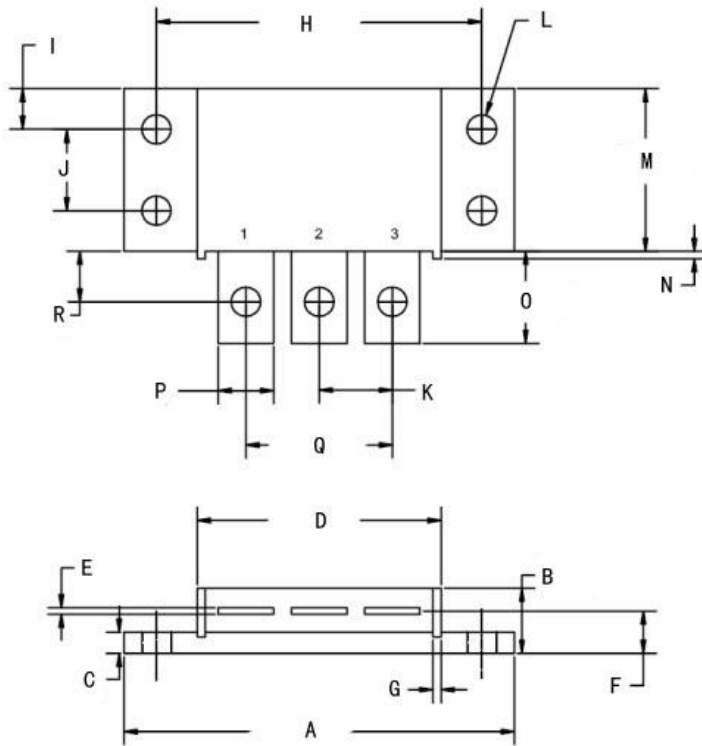


Figure 3
Reverse Voltage - V_R (V)
Typical Junction Capacitance

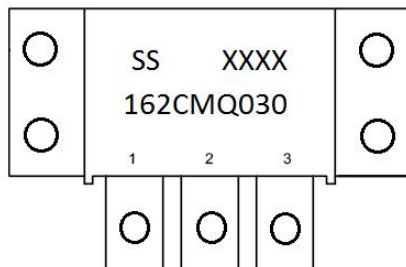


Ordering Information

Device	Package	Shipping
162CMQ030	TO-249AA(Pb-Free)	24pcs/ box

Mechanical Dimensions TO-249AA (Inches/Millimeters)


SYMBOL	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	60.38	61.58	2.377	2.424
B	8.38	10.16	0.330	0.400
C	2.77	3.57	0.109	0.141
D	37.00	38.20	1.457	1.504
E	0.62	1.32	0.024	0.052
F	6.35		0.250	
G	1.27		0.050	
H	50.80		2.000	
I	6.35		0.250	
J	12.70		0.500	
K	11.43		0.450	
L	4.35	5.05	0.171	0.199
M	24.90	25.90	0.980	1.020
N	0.64	1.26	0.025	0.050
O	11.80	13.51	0.465	0.532
P	8.64		0.340	
Q	22.86		0.900	
R	7.93		0.312	

Marking Diagram


Where XXXX is YYWW

1st row SS YYWW
 2nd row 162CMQ030
 3rd row 1 2 3 (pin)
 SS = SS
 YY = Year
 WW = Week

Cautions: Molding resin
 Epoxy resin UL:94V-0

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